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January 2015

FSA839 — Low-Voltage, 0.8 Ω SPDT Analog Switch with Power-Off Isolation

Description

make operation.

The FSA839 is a high-performance Single-Pole /

Double-Throw (SPDT) analog switch for audio

applications driven by low-voltage (1.8 V) baseband processors or ASICs. The device features ultra-low R_{ON}

of 0.8 Ω (maximum) at 4.5 V V_{CC} and operates over the

wide V_{CC} range of 1.65 V to 5.5 V. The device is fabricated with sub-micron CMOS technology to achieve

fast switching speeds and is designed for break-before-

The FSA839 interfaces between the low-voltage ASIC

and regular audio amplifiers and CODECs operating up to a 5.5 V supply range. The control circuitry allows for

1.8 V (typical) signals on the control pin (Sel).

Features

- Power-Off Isolation (V_{CC}=0 V)
- = 0.8 Ω Maximum On Resistance (R_{ON}) for 4.5 V V_{CC}
- 0.25 Ω Maximum R_{ON} Flatness for 4.5 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Fast Turn-On and Turn-Off Times
- Control Input Switching Thresholds Independent of V_{CC}
- Break-Before-Make Enable Circuitry
- 0.4 mm WLCSP Packaging
- ESD Performance
 - HBM per JESD22-A114, I/O to GND: 8 kV
 - CDM per JESD22-C101: 500 V
 - IEC61000-4-2 Contact / Air: 8 kV / 15 kV

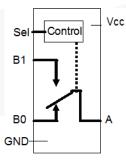
Applications

- Cellular Phone
- Portable Media Player
- PDA

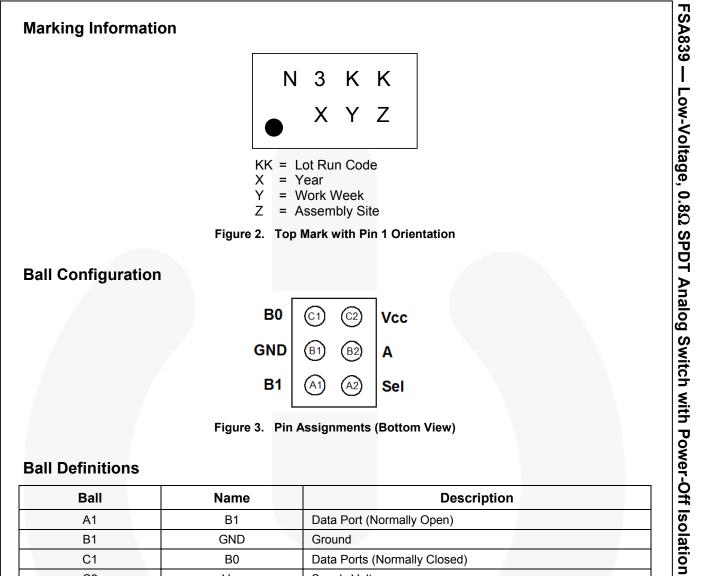
Ordering Information

Part Number	Operating Temperature Range	Top Mark	Package	Packing Method
FSA839UCX	-40°C to +85°C	N3	6-Ball WLCSP, 0.4 mm Pitch	Tape and Reel

Ø For Fairchild's definition of "green" Eco Status, please visit: <u>http://www.fairchildsemi.com/company/green/rohs_green.html.</u>







Ball	Name	Description	
A1	B1	Data Port (Normally Open)	
B1	GND	Ground	
C1	B0	Data Ports (Normally Closed)	
C2	V _{cc}	Supply Voltage	
B2	A	Common Data Port	
A2	Sel	Control Input	

Truth Table

Control Input (Sel)	Function
LOW	B0 connected to A
HIGH	B1 connected to A

2

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Min.	Max.	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{SW}	Switch Voltage ⁽¹⁾		-0.5	V _{CC} + 0.5	V
V _{IN}	Input Voltage ⁽¹⁾		-0.5	6.5	V
I _{IK}	Input Diode Current			-50	mA
I _{SW}	Switch Current (Continuous)			200	mA
I _{SWPEAK}	Peak Switch Current (Pulsed at 1 ms Duration, <10%	% Duty Cycle)		400	mA
PD	Power Dissipation at 85°C			180	mW
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Maximum Junction Temperature			+150	°C
TL	Lead Temperature (Soldering, 10 Seconds)			+260	°C
	Human Bady Madal (JEDEC: JECD22 A114)	I/O to GND: A		8	
	Human Body Model (JEDEC: JESD22-A114)	All Pins		2	kV
ESD	Charged Device Model (JEDEC: JESD22-C101)			500	V
ESD	Machine Model (JEDEC: JESD22-A115)			100	V
	IEC6100-4-2 Discharge System Test Performed on Fairchild's FSA859 Applications Testing Board Contact Air			8	kV
				15	κV

Note:

1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{cc}	Supply Voltage	1.65	5.50	V
SEL	Control Input Voltage	0	1.95	V
V _{sw}	Switch Input Voltage	0	V _{cc}	V
T _A	Operating Temperature	-40	+85	°C
θ_{JA}	Thermal Resistance, Still Air		350	°C/W

FSA839
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DC Electrical Characteristics

All typical values are at 25°C unless otherwise specified.

Symbol	Parameter	V _{cc} (V)	Conditions	Т	_A =+25°	с	T _A =-40 to +85°C		Unit
		,		Min.	Тур.	Max.	Min.	Max.	
V _{IH}	Input Voltage High	1.65 to 5.50					1.0		V
V _{IL}	Input Voltage Low	1.65 to 5.50						0.57	V
I _{IN}	Control Input Leakage	1.95 to 5.50	V _{Sel} =0	-2		2	-20	20	nA
		5.50	A=1 V, 4.5 V B0 or B1=4.5, 1 V	-10		10	-50	50	
I _{NO(0FF),}	Off-Leakage Current of Port B0	3.60	A=1 V, 3.0V B0 or B1=3.0, 1V	-10		10	-50	50	nA
I _{NC(OFF)} ,	and B1 ⁽⁵⁾	2.70	A=0.5 V, 2.3 V B0 or B1=2.3, 0.5V	-10		10	-50	50	ΠA
		1.95	A=0.3 V, 1.65 V B0 or B1=1.65 ,0.3 V	-5		5	-20	20	
	$I_{NO(On),}$ $I_{NC(On)}$ On-Leakage Current of Port B0 and B1 ⁽⁵⁾	5.50	A=Floating B0 or B1=4.5, 1V	-20		20	-100	100	
I _{NO(On),}		3.60	A=Floating B0 or B1=3.0, 1 V	-10		10	-20	20	– nA
		2.70	A=Floating B0 or B1=2.3, 0.5 V	-10		10	-20	20	
		1.95	A=Floating B0 or B1=1.65, 0.3 V	-5		5	-20	20	
	5.50	A=1 V, 4.5 V; B0 or B1=1 V, 4.5 V, or Floating	-20		20	-100	100		
	On Leakage	3.60	A=1V, 3.0VB0 or B1=1V, 3.0V, or Floating	-10		10	-20	20	
I _{A(ON)}	Current of Port A ⁽⁵⁾	2.70	A=0.5 V, 2.3 V, B0 or B1=0.5 V, 2.3 V, or Floating	-10		10	-20	20	nA
		1.95	A=0.3 V, 1.65 V; B0 or B1=0.3 V, 1.65 V, or Floating	-5		5	-20	20	
I _{OFF}	Power Off Leakage Current of Port A & Port B ⁽⁵⁾	0	A=0 to 5.5 V B0 or B1=0 to 5.5 V	-1.00	0.01	1.00	-5.00	5.00	μA
R_{PD}	Sel Internal Pull- Down Resistor	1.65 to 1.95			2.0				MΩ
. Quiescent		5.50	V_{IN} , V_{SEL} =0 or V_{CC} , I_{OUT} =0			100		500	
	Quiescent Supply	3.60	V_{IN} , V_{SEL} =0 or V_{CC} , I_{OUT} =0			75		300	~
I _{CC}	Current	2.70	V_{IN} , V_{SEL} =0 or V_{CC} , I_{OUT} =0			50		250	nA
		1.95	V_{IN} , V_{SEL} =0 or V_{CC} , I_{OUT} =0			25		150	

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DC Electrical Characteristics (Continued)

All typical values are at 25°C unless otherwise specified.

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Symbol	Parameter	V _{cc} (V)	Conditions	Min.	Тур.	Max.	Min.	Max.	Unit
		5.50	V _{Sel} = 1.8 V		26	40		50	
	Increase in I _{CC} per Control	3.60	V _{Sel} = 1.8 V		5	15		20	
I _{CCT}	Input	2.70	V _{Sel} = 1.8 V		1	5		10	μA
		1.95	V _{Sel} = 1.8 V		0.01	1.00		3.00	
I _{CCZ}	Supply Current Sleep	5.50	V _{IN} , V _{Sel} = Floating			0.5		1.0	μA
		4.50	I _{OUT} =-100 mA, B0 or B1=2.5 V		0.50	0.75		0.80	
D	Switch On	3.00	I _{OUT} =-100 mA, B0 or B1=2.0 V		0.75	0.90		1.20	Ω
RON	R _{ON} Resistance ^(2,5)	2.25	I _{OUT} =-100 mA, B0 or B1=1.8 V		1.0	1.3		1.6	12
		1.65	I _{OUT} =-100 mA, B0 or B1=1.2 V		2.5	5.0		7.0	
		4.50	I _{OUT} =-100 mA, B0 or B1=2.5 V		0.05	0.10		0.10	
	On Resistance Matching	3.00	I _{OUT} =-100 mA, B0 or B1=2.0 V		0.10	0.15		0.15	Ω
ΔR_{ON}	Between Channels ^(3,5)	2.25	I _{OUT} =-100 mA, B0 or B1=1.8 V		0.15	0.20		0.20	12
		1.65	I _{OUT} =-100 mA, B0 or B1=1.2 V		0.15	0.40		0.40	
		4.50	I _{OUT} =-100 mA, B0 or B1=1.0V, 1.5 V, 2.5 V		0.075	0.250		0.250	
R _{FLAT(ON)} On Resistance Flatness ^(4,5)	3.00	I _{OUT} =-100 mA, B0 or B1=0.8 V, 2.0 V		0.1	0.3		0.3		
	2.25	I _{OUT} =-100 mA, B0 or B1=0.8 V, 1.8 V		0.25	0.50		0.60	Ω	
		1.65	I _{OUT} =-100mA, B0 or B1=0.6 V, 1.2 V		3.5				

FSA839 — Low-Voltage, 0.8Ω SPDT Analog Switch with Power-Off Isolation

Notes:

2. On resistance is determined by the voltage drop between A and B pins at the indicated current through the switch.

3. $\Delta R_{ON} = R_{ON}$ maximum – R_{ON} minimum; measured at identical V_{CC}, temperature, and voltage.

4. Flatness is defined as the difference between the maximum and minimum value of on resistance over the specified range of conditions.

5. Guaranteed by characterization, not production tested for V_{CC} =1.65 – 1.95 V.

Symbol Parameter	V _{cc} (V)	Conditions	T _A =+25°C		T _A =-40 to +85°C		Unit	Figure		
				Min.	Тур.	Max.	Min.	Max.		-
	, Turn-On	4.50 to 5.50		1.0	12.0	25.0	1.0	30.0		
		3.00 to 3.60	B0 or B1=V _{CC} ,	5.0	15.0	30.0	3.0	35.0		Figure
t _{ON}	Time ⁽⁶⁾	2.30 to 2.70	R _L =50 Ω, C _L =35 pF	5.0	20.0	35.0	5.0	40.0	ns	4
		1.65 to 1.95		10.0	50.0	70.0	10.0	75.0		
		4.50 to 5.50		1.0	9.5	20.0	1.0	25.0		
		3.00 to 3.60	B0 or B1=V _{CC} ,	1.0	9.0	20.0	1.0	25.0		
t_{OFF}	Turn-Off Time ⁽⁶⁾	2.30 to 2.70	$R_L=50 \Omega,$ C _L =35 pF	2.0	10.0	20.0	2.0	25.0	ns	Figure 4
		1.65 to 1.95		2.0	28.0	40.0	2.0	50.0		
_		4.50 to 5.50		1.0	10.0	12.0	0.1	14.0		
	Break- Before-	3.00 to 3.60	B0 or B1=V _{CC} /2,	1.0	14.0	16.0	1.0	17.0		Figure
t _{BBM} Make Time ⁽⁷⁾	2.30 to 2.70	R _L =50 Ω, C _L =35 pF	1.0	21.0	25.0	1.0	27.0	ns	5	
	Time ⁽⁷⁾	1.65 to 1.95			35.0		2.0	50.0		
		5.50			70				pC	Figure 7
	Charge	3.30	C _L =1.0 nF,		40					
Q	Injection	2.50	V _{GEN} =0 V, R _{GEN} =0 Ω		30					
		1.65	I GEN 0 11		10					
OIRR	Off Isolation	1.8 to 5.0	f=1 MHz, R _L =50 Ω		-55				dB	Figure 6
Xtalk	Crosstalk	1.8 to 5.0	f=1 MHz, R _L =50 Ω		55				dB	Figure 6
		5.50			60					
	-3 db	3.30	D -50 0		60					Figure
BW	Bandwidth	2.50	R _L =50 Ω		55				MHz	9
		1.65			50					6
	Total	1.80	R _L =600 Ω, V _{IN} =0.5 V _{PP} ,		.02					Figure
THD Harmonic Distortion		5.00	f=20 Hz to 20 kHz		.001				%	10
PSRR	Power Supply Rejection Ratio	3.3	f=217 Hz on V _{CC} at 500 mvpp		-23				dB	Figure 11

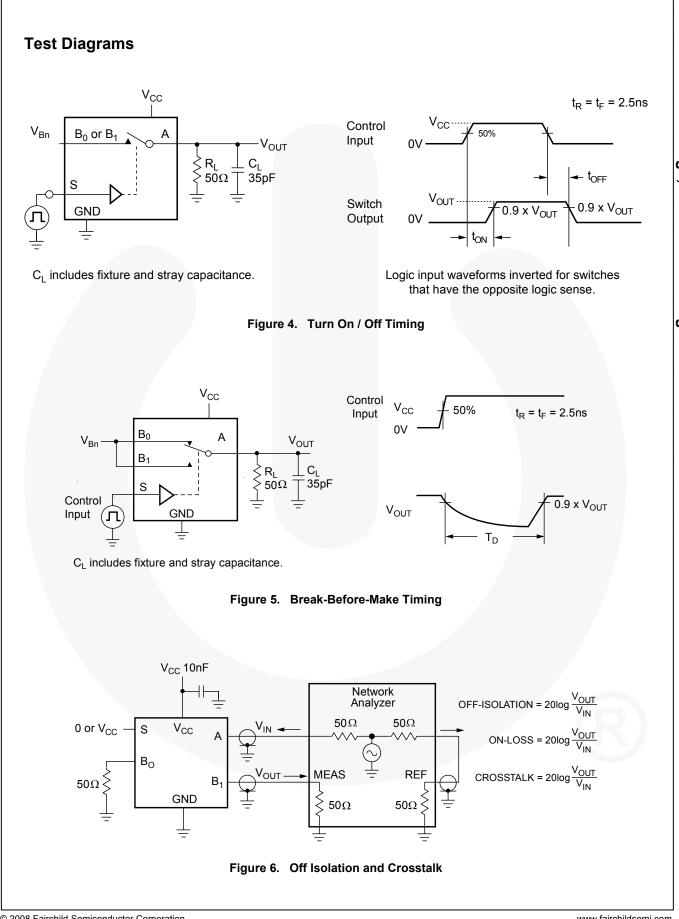
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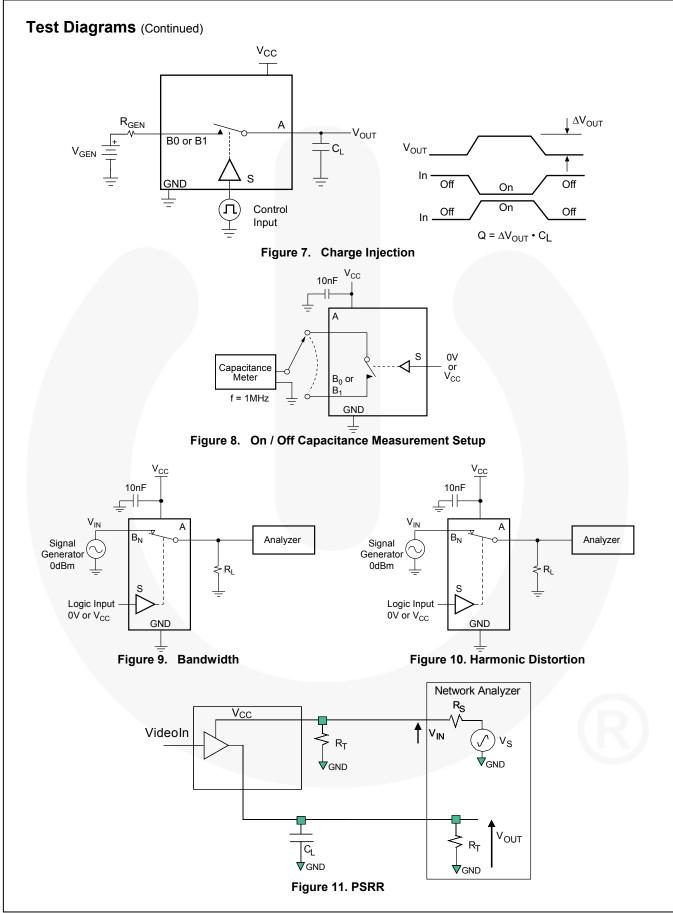
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7.

Capacitance

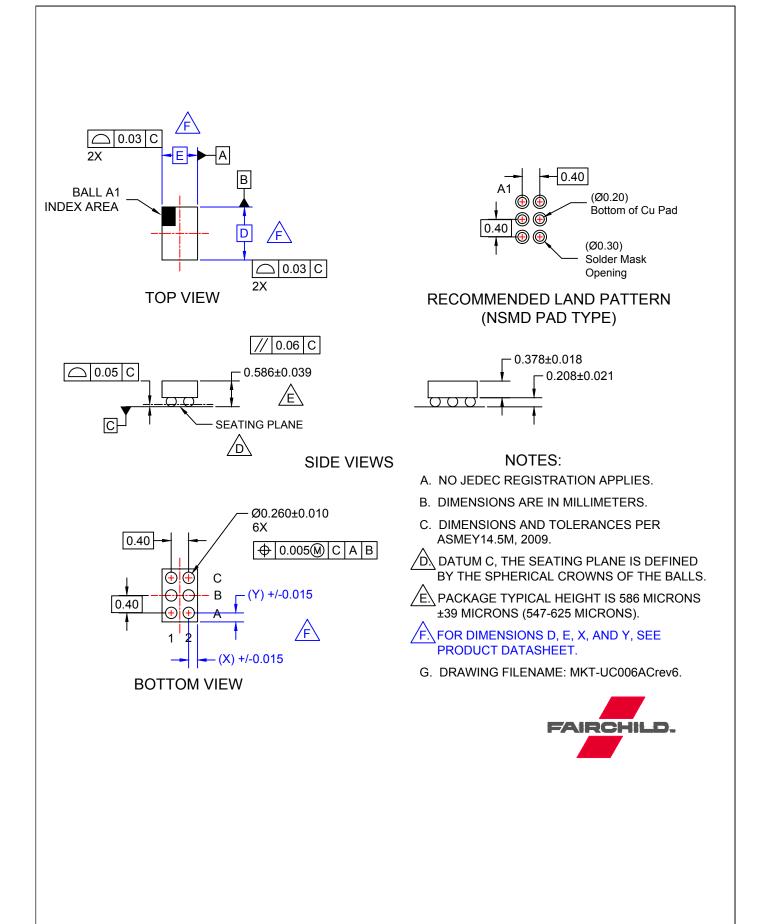
Symbol	Parameter		Conditions	T _{A=} +25⁰C			Unit	
Symbol	Farameter	V _{cc} (V)	Conditions	Min.	Тур.	Max.	Unit	
CIN	Control Pin Input Capacitance	0	f=1 MHz		3.2		pF	
C _{OFF}	B Port Off Capacitance	1.65 to 5.50	f=1 MHz		50		pF	
C _{ON}	A Port On Capacitance	1.65 to 5.50	f=1 MHz		150		pF	

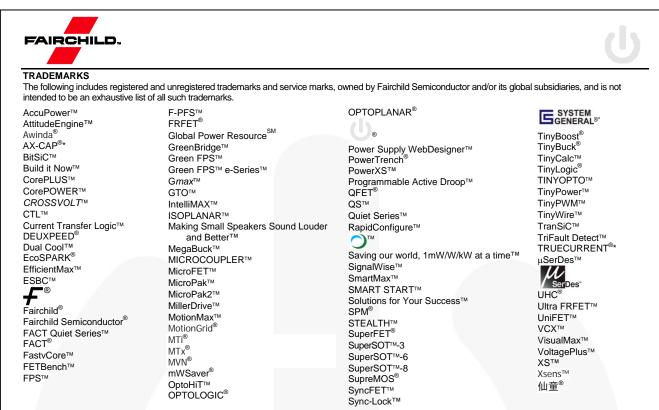




FSA839 — Low-Voltage, 0.8Ω SPDT Analog Switch with Power-Off Isolation

Product	D	E	Х	Y
FSA839UCX	1.160 ±.030	0.760 ±.030	0.180	0.180





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